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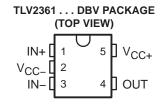
Low Supply-VoltageOperation . . . V_{CC} = ±1 V Min

 Wide Bandwidth . . . 7 MHz Typ at V_{CC}± = ±2.5 V

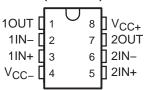
 High Slew Rate . . . 3 V/μs Typ at V_{CC}± = ±2.5 V

• Wide Output Voltage Swing . . . ± 2.4 V Typ at V_{CC} $\pm = \pm 2.5$ V, R_L = 10 k Ω

• Low Noise . . . 8 nV/ $\sqrt{\text{Hz}}$ Typ at f = 1 kHz



TLV2362 . . . D, DGK, P, PS, OR PW PACKAGE (TOP VIEW)



description/ordering information

The TLV236x devices are high-performance dual operational amplifiers built using an original Texas Instruments bipolar process. These devices can be operated at a very low supply

voltage (± 1 V), while maintaining a wide output swing. The TLV236x devices offer a dramatically improved dynamic range of signal conditioning in low-voltage systems. The TLV236x devices also provide higher performance than other general-purpose operational amplifiers by combining higher unity-gain bandwidth and faster slew rate. With their low distortion and low-noise performance, these devices are well suited for audio applications.

ORDERING INFORMATION

TA	PACKAGE	it .	ORDERABLE PART NUMBER	TOP-SIDE MARKING [‡]
000 to 7000	COT 00 5 (DD)/\	Reel of 3000	TLV2361CDBVR	VCa
−0°C to 70°C	SOT-23-5 (DBV)	Reel of 250	TLV2361CDBVT	YC3_
	COT 00 5 (DD)/\	Reel of 3000	TLV2361IDBVR	VC4
	SOT-23-5 (DBV)	Reel of 250	TLV2361IDBVT	YC4_
	MSOP/VSSOP (DGK)	Reel of 2500	TLV2362IDGKR	YBS
	PDIP (P)	Tube of 50	TLV2362IP	TLV2362IP
-40°C to 85°C	0010 (D)	Tube of 75	TLV2362ID	00001
	SOIC (D)	Reel of 2500	TLV2362IDR	23621
	SOP (PS)	Reel of 2000	TLV2362IPSR	TY2362
	TCCOD (DW)	Tube of 150	TLV2362IPW	TV0000
	TSSOP (PW)	Reel of 2000	TLV2362IPWR	TY2362

[†] Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



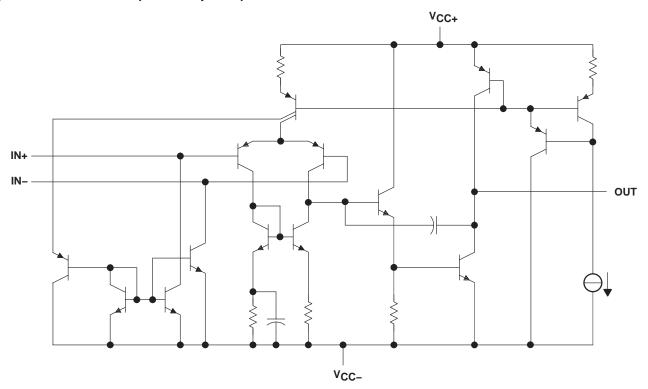
Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



[‡]DBV: The actual top-side marking has one additional character that designates the wafer fab/assembly site.

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equivalent schematic (each amplifier)



ACTUAL DEVICE COMPONENT COUNT							
COMPONENT TLV2361 TLV2362							
Transistors	30	46					
Resistors	6	11					
Diodes	1	1					
Capacitors	2	4					
JFET	1	1					

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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage, V _{CC+} (see Note 1)		3.5 V
Supply voltage, V _{CC} (see Note 1)		3.5 V
Differential input voltage, V _{ID} (see Note 2)		±3.5 V
Input voltage, V _I (any input) (see Notes 1 and 3)		V _{CC} ±
Output voltage, VO		
Output current, IO		20 mA
Duration of short-circuit current at (or below) 25°C (ou	tput shorted to GND)	Unlimited
Package thermal impedance, θ _{JA} (see Notes 4 and 5)): D package	97°C/W
	DBV package	206°C/W
	DGK package	172°C/W
	P package	85°C/W
	PS package	95°C/W
	PW package	149°C/W
Operating virtual junction temperature, T _J		150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10		
Storage temperature range, T _{stg}		-65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. All voltage values, except differential voltages, are with respect to the midpoint between V_{CC+} and V_{CC-}.

- 2. Differential voltages are at IN+ with respect to IN-.
- All input voltage values must not exceed V_{CC}.
 Maximum power dissipation is a function of T_J(max), θ_{JA}, and T_A. The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(max) - T_A)/\theta_{JA}$. Selecting the maximum of 150°C can affect reliability.
- 5. The package thermal impedance is calculated in accordance with JESD 51-7.

recommended operating conditions

			MIN	MAX	UNIT
VCC	Supply voltage		±1	±2.5	V
т.	Operating two oir temperature	TLV2361C	0	70	٠ 2
۱A	Operating free-air temperature	TLV2361I, TLV2362I	-40	85	٠.

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TLV2361 and TLV2362 electrical characteristics, $V_{CC}\pm$ = ± 1.5 V (unless otherwise noted)

	PARAMETER	TE	ST CONDITIONS		TA	MIN	TYP	MAX	UNIT
V	Input offset voltage	V 0	V _{IC} = 0		25°C		1	6	mV
V _{IO}	input onset voltage	$V_{O} = 0,$	ΔIC = 0		Full range			7.5	IIIV
li o	Input offset current	$V_{O} = 0$,	V _{IC} = 0		25°C		5	100	nA
IIO	input onset current	V() = 0,	ΔIC = 0		Full range			150	IIA
l.s	Input bias current	Vo = 0	V/: a = 0		25°C		20	150	nA
I _{IB}	input bias current	VO = 0,	$V_O = 0,$ $V_{IC} = 0$					250	IIA
V/	Common-mode input				25°C	±0.5			V
VIC	voltage	V O ≥ 1.5 mv	V _{IO} ≤ 7.5 mV			±0.5			V
V	Maximum positive-peak	ak $R_L = 10 \text{ k}\Omega$ 25°C	$R_L = 10 \text{ k}\Omega$		25°C	1.2	1.4		V
V _{OM} +	output voltage	$R_L \ge 10 \text{ k}\Omega$			Full range	1.2			V
V	Maximum negative-peak	$R_L = 10 \text{ k}\Omega$			25°C	-1.2	-1.4		V
VOM-	output voltage	$R_L \ge 10 \text{ k}\Omega$			Full range	-1.2			V
1	Supply current	\/ ₂ 0	No load		25°C		1.4	2.25	mA
Icc	(per amplifier)	$V_{O} = 0,$	No load		Full range			2.75	mA
Δ	Large-signal differential	V- 14 V	D. 40 kO	TLV2361	2500	60	80		dB
AVD	voltage amplification	$V_O = \pm 1 \text{ V}, \qquad \qquad R_L = 10 \text{ k}\Omega$		TLV2362	25°C		55		uБ
CMRR	Common-mode rejection ratio	V _{IC} = ±0.5 V			25°C		75		dB
ksvR	Supply-voltage rejection ratio	V _{CC} ± = ±1.5 V t	to ±2.5 V		25°C		80		dB

TLV2361 and TLV2362 operating characteristics, $V_{CC}\pm$ = ±1.5 V, T_A = 25°C

	PARAMETER		TEST CONDITIONS		TYP	UNIT
SR	Slew rate	$A_V = 1$,	$V_{I} = \pm 0.5 V$		2.5	V/μs
В1	Unity-gain bandwidth	Ay = 40,	$R_L = 10 \text{ k}\Omega$,	C _L = 100 pF	6	MHz
Vn	Equivalent input noise voltage	$R_S = 100 \Omega$,	$R_F = 10 \text{ k}\Omega$,	f = 1 kHz	9	nV/√ Hz

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TLV2361 and TLV2362 electrical characteristics, $V_{CC}\pm$ = ± 2.5 V (unless otherwise noted)

	PARAMETER TEST CONDITIONS		TA	MIN	TYP	MAX	UNIT		
V/	Input offeet voltage	V- 0	\/ O		25°C		1	6	mV
V _{IO}	Input offset voltage	$V_{O} = 0,$	V _{IC} = 0		Full range			7.5	IIIV
1	Input offset current	V = - 0	\/· = - 0		25°C		5	100	nA
lio	input onset current	$V_{O} = 0,$	V _{IC} = 0		Full range			150	IIA
1	Innut hing gurrant	V- 0	V/ 0		25°C		20	150	~ A
I _{IB}	Input bias current	$V_O = 0$,	VIC = 0		Full range			250	nA
\/	Common-mode input	N/: -1 < 7.5 m)/			25°C	±1.5			.,
VIC	voltage	$ V_{IO} \le 7.5 \text{ mV}$			Full range	±1.4			V
V	Maximum positive-peak	$R_L = 10 \text{ k}\Omega$			25°C	2	2.4		V
V _{OM+}	output voltage	$R_L \ge 10 \text{ k}\Omega$			Full range	2			V
\/	Maximum negative-peak	$R_L = 10 \text{ k}\Omega$			25°C	-2	-2.4		V
VOM-	output voltage	$R_L \ge 10 \text{ k}\Omega$			Full range	-2			V
1	Supply current	\/- 0	Nelsed		25°C		1.75	2.5	^
Icc	(per amplifier)	$V_O = 0$,	No load		Full range			3	mA
۸	Large-signal differential	\/- \(\(\) \/ \(\)	D: 40 l-0	TLV2361	2500	60	80		dB
AVD	voltage amplification	$V_0 = \pm 1 V$,	$R_L = 10 \text{ k}\Omega$	TLV2362	25°C		60		aв
CMRR	Common-mode rejection ratio	V _{IC} = ±0.5 V			25°C		85		dB
ksvr	Supply-voltage rejection ratio	V _{CC} ± = ±1.5 V	to ±2.5 V		25°C		80		dB

TLV2361 and TLV2362 operating characteristics, V_{CC \pm} = \pm 2.5 V, T_A = 25°C

	PARAMETER		TEST COND	DITIONS	TYP	UNIT
SR	Slew rate	$A_V = 1$,	$V_{I} = \pm 0.5 \ V$		3	V/μs
B ₁	Unity-gain bandwidth	$A_{V} = 40,$	$R_L = 10 \text{ k}\Omega$,	C _L = 100 pF	7	MHz
V _n	Equivalent input noise voltage	$R_S = 100 \Omega$,	$R_F = 10 \text{ k}\Omega$,	f = 1 kHz	8	nV/√ Hz
THD + N	Total harmonic distortion, plus noise	$A_V = 1$,	$V_0 = \pm 1.2 V$,	$R_L = 10 \text{ k}\Omega$, $f = 3 \text{ kHz}$	0.004	%

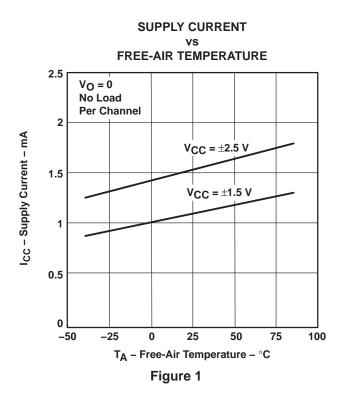
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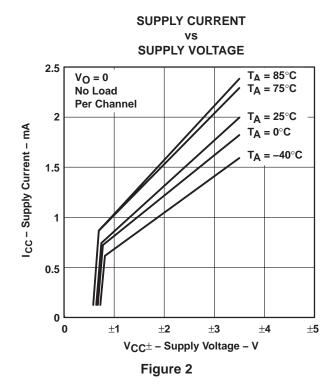
TYPICAL CHARACTERISTICS

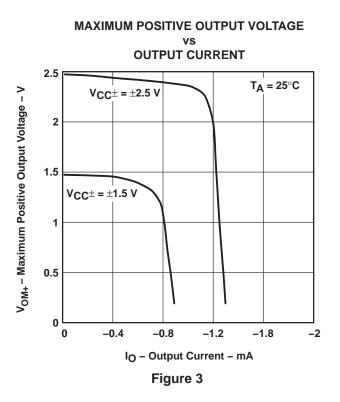
Table of Graphs

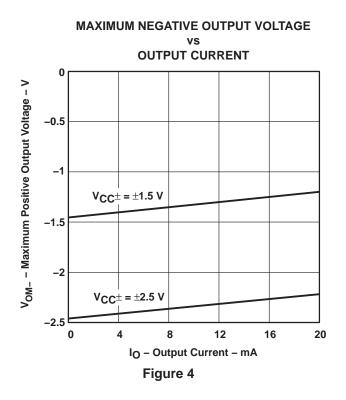
GRAPH TITLE	FIGURE
Supply current vs Free-air temperature	1
Supply current vs Supply voltage	2
Maximum positive output voltage vs Output current	3
Maximum negative output voltage vs Output current	4
Maximum peak-to-peak output voltage vs Frequency	5
Equivalent input noise voltage vs Frequency	6
Total harmonic distortion vs Frequency	7
Total harmonic distortion vs Output voltage	8

TYPICAL CHARACTERISTICS





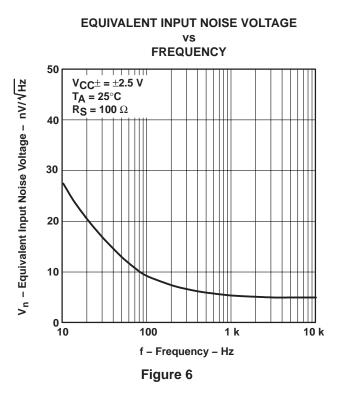


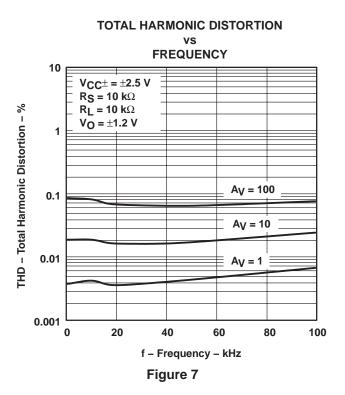


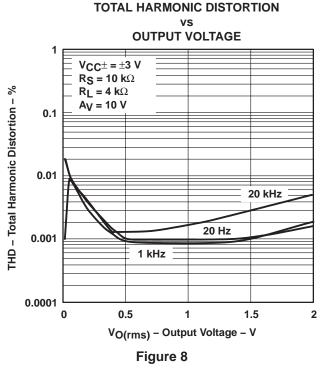
TYPICAL CHARACTERISTICS

MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE **FREQUENCY** V_{O(PP)} - Maximum Peak-to-Peak Output Voltage - V $V_{CC} \pm = \pm 2.5 \text{ V}$ 3 $V_{CC} \pm = \pm 1.5 \text{ V}$ 2 1 $T_A = 25^{\circ}C$ $R_L = 10 \text{ k}\Omega$ 0 100 k 1 k 10 k 1 M 10 M f - Frequency - Hz

Figure 5









PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
TLV2361CDBV	OBSOLETE	SOT-23	DBV	5		TBD	Call TI	Call TI
TLV2361CDBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLV2361CDBVRE4	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLV2361CDBVRG4	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLV2361CDBVT	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLV2361CDBVTE4	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLV2361CDBVTG4	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLV2361IDBV	OBSOLETE	SOT-23	DBV	5		TBD	Call TI	Call TI
TLV2361IDBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLV2361IDBVRE4	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLV2361IDBVRG4	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLV2361IDBVT	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLV2361IDBVTE4	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLV2361IDBVTG4	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLV2362ID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLV2362IDE4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLV2362IDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLV2362IDGKR	ACTIVE	MSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLV2362IDGKRG4	ACTIVE	MSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLV2362IDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLV2362IDRE4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLV2362IDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLV2362IP	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
TLV2362IPE4	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
TLV2362IPSR	ACTIVE	SO	PS	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLV2362IPSRE4	ACTIVE	SO	PS	8	2000	Green (RoHS &	CU NIPDAU	Level-1-260C-UNLIM





27-Jun-2007

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
						no Sb/Br)		
TLV2362IPSRG4	ACTIVE	SO	PS	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLV2362IPW	ACTIVE	TSSOP	PW	8	150	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLV2362IPWE4	ACTIVE	TSSOP	PW	8	150	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLV2362IPWG4	ACTIVE	TSSOP	PW	8	150	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLV2362IPWLE	OBSOLETE	TSSOP	PW	8		TBD	Call TI	Call TI
TLV2362IPWR	ACTIVE	TSSOP	PW	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLV2362IPWRE4	ACTIVE	TSSOP	PW	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLV2362IPWRG4	ACTIVE	TSSOP	PW	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

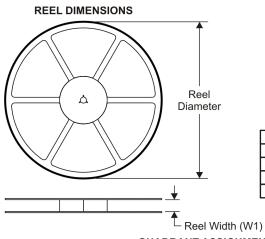
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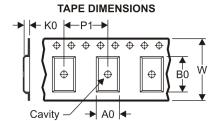




21-Mar-2008

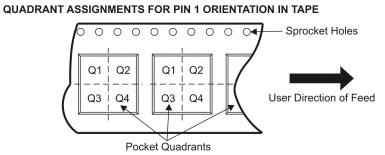
TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

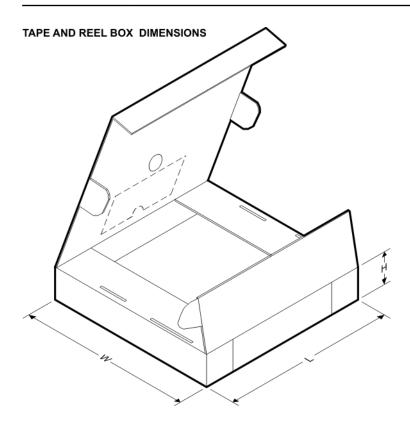
— Reel Width (WT)



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TLV2361CDBVR	SOT-23	DBV	5	3000	180.0	9.2	3.23	3.17	1.37	4.0	8.0	Q3
TLV2361CDBVT	SOT-23	DBV	5	250	179.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TLV2361CDBVT	SOT-23	DBV	5	250	180.0	9.2	3.23	3.17	1.37	4.0	8.0	Q3
TLV2361IDBVR	SOT-23	DBV	5	3000	180.0	9.2	3.23	3.17	1.37	4.0	8.0	Q3
TLV2361IDBVT	SOT-23	DBV	5	250	180.0	9.2	3.23	3.17	1.37	4.0	8.0	Q3
TLV2362IDGKR	MSOP	DGK	8	2500	330.0	13.0	5.3	3.4	1.4	8.0	12.0	Q1
TLV2362IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLV2362IPSR	SO	PS	8	2000	330.0	16.4	8.2	6.6	2.5	12.0	16.0	Q1
TLV2362IPWR	TSSOP	PW	8	2000	330.0	12.4	7.0	3.6	1.6	8.0	12.0	Q1





*All dimensions are nominal

7 til dillionololle are nominal							
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TLV2361CDBVR	SOT-23	DBV	5	3000	205.0	200.0	33.0
TLV2361CDBVT	SOT-23	DBV	5	250	195.0	200.0	45.0
TLV2361CDBVT	SOT-23	DBV	5	250	201.0	192.0	26.0
TLV2361IDBVR	SOT-23	DBV	5	3000	205.0	200.0	33.0
TLV2361IDBVT	SOT-23	DBV	5	250	201.0	192.0	26.0
TLV2362IDGKR	MSOP	DGK	8	2500	358.0	335.0	35.0
TLV2362IDR	SOIC	D	8	2500	340.5	338.1	20.6
TLV2362IPSR	SO	PS	8	2000	346.0	346.0	33.0
TLV2362IPWR	TSSOP	PW	8	2000	346.0	346.0	29.0

DBV (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE



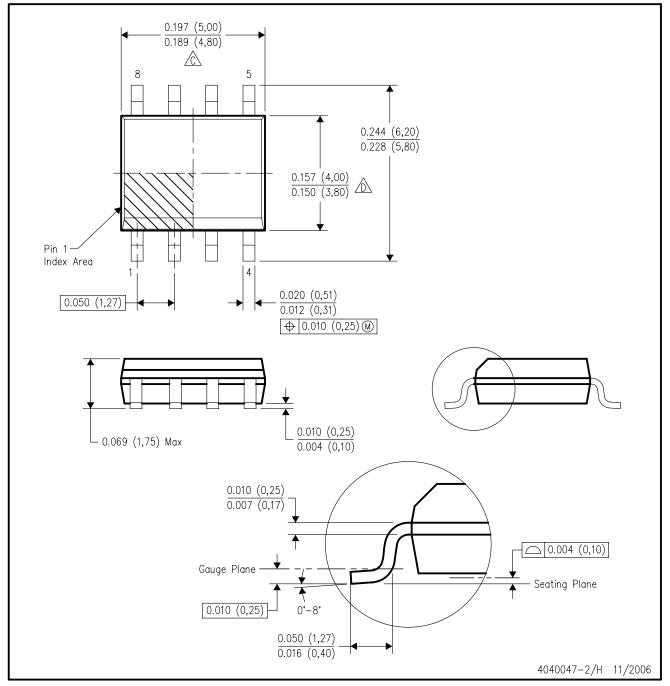
NOTES:

- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
 - D. Falls within JEDEC MO-178 Variation AA.



D (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 (0,15) per end.
- Body width does not include interlead flash. Interlead flash shall not exceed .017 (0,43) per side.
- E. Reference JEDEC MS-012 variation AA.



PW (R-PDSO-G**)

14 PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

DGK (S-PDSO-G8)

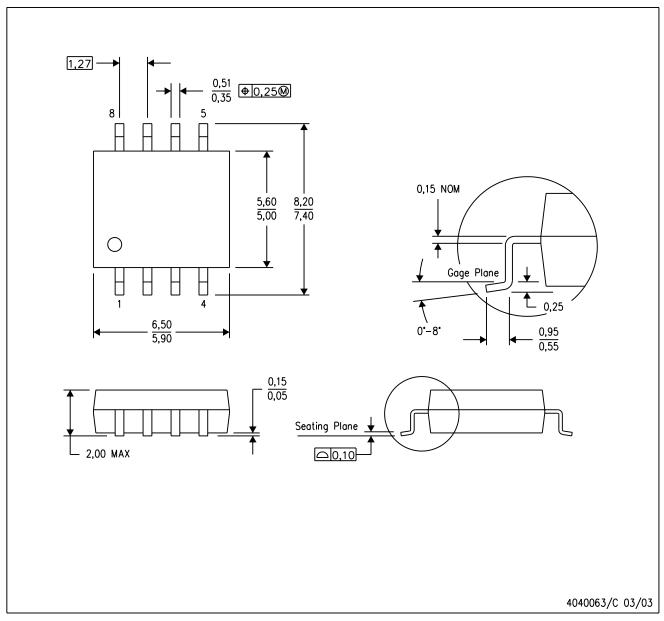
PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 per end.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.50 per side.
- E. Falls within JEDEC MO-187 variation AA, except interlead flash.





NOTES: A. All linear dimensions are in millimeters.

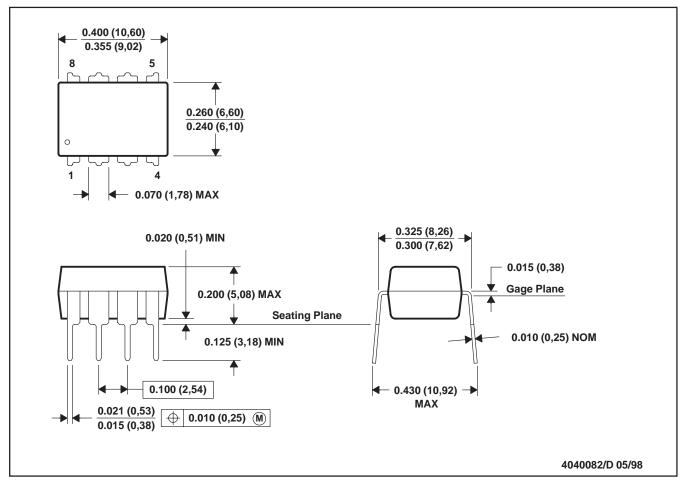
B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



P (R-PDIP-T8)

PLASTIC DUAL-IN-LINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-001

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